

# isc N-Channel MOSFET Transistor

## IXTH220N055T

#### • FEATURES

- Static drain-source on-resistance:
  RDs(on) ≤ 4.0mΩ@V<sub>GS</sub>=10V
- Fully characterized avalanche voltage and current
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

#### APPLICATION

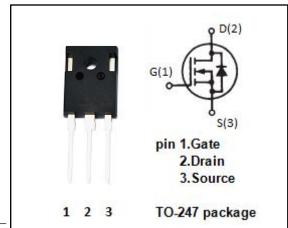
- DC/DC Converters
- High Current Switching Applications

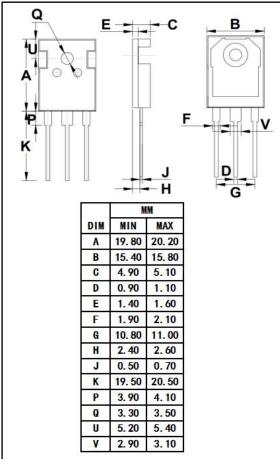
### • ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT	
$V_{DSS}$	Drain-Source Voltage	55	٧	
$V_{GS}$	Gate-Source Voltage	±20	V	
I <sub>D</sub>	Drain Current-Continuous	220	А	
I <sub>DM</sub>	Drain Current-Single Pulsed	600	Α	
P <sub>D</sub>	Total Dissipation @Tc=25°C	430	W	
Tj	Operating Junction Temperature	-55~175	$^{\circ}$	
T <sub>stg</sub>	Storage Temperature	-55~175	$^{\circ}$	

### • THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
$R_{\text{th(j-c)}}$	Junction-to-case thermal resistance	0.35	°C/W







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#### **ELECTRICAL CHARACTERISTICS**

T<sub>C</sub>=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	MAX	UNIT
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V; ID = 250 μ A	55		V
V <sub>GS(th)</sub>	Gate Threshold Voltage	V <sub>DS</sub> =V <sub>GS</sub> ; ID = 250 μ A	2.0	4.0	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> =10V; I <sub>D</sub> = 25A		4.0	mΩ
I <sub>GSS</sub>	Gate-Source Leakage Current	V <sub>GS</sub> = ±20V;V <sub>DS</sub> =0V		±200	nA
I <sub>DSS</sub>	Drain-Source Leakage Current	V <sub>DS</sub> = V <sub>DSS</sub> ; V <sub>GS</sub> = 0V		5	μ Α
		V <sub>DS</sub> = V <sub>DSS</sub> ; V <sub>GS</sub> = 0V;T <sub>J</sub> = 150°C		250	
Vsp	Diode forward voltage	I <sub>F</sub> = 25A; V <sub>GS</sub> = 0V		1.0	V



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